



### 40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	I <sub>D</sub> Tc = +25°C
-40V	5.2mΩ @ V <sub>GS</sub> = -10V	-115A
-40 V	7.9mΩ @ V <sub>GS</sub> = -6V	-94A

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Reverse Polarity Protection
- BLDC Motor Control
- Power Management Functions
- System/Load Switch

#### **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- · Fast Switching Speed
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4006SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

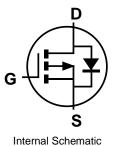
### **Mechanical Data**

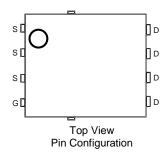
- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

### PowerDI5060-8 (SWP) (Type UX)



Top View Bottom View





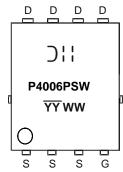
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMP4006SPSWQ-13	PowerDI5060-8 (SWP) (Type UX)	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



PowerDI is a registered trademark of Diodes Incorporated.



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-40	V		
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	lD	-115 -92	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-460	Α		
Maximum Body Diode Continuous Current	Is	-115	Α		
Pulsed Source Current (10µs Pulse, Duty Cycle = 19	lsм	-460	Α		
Avalanche Current (L = 0.1mH)			las	-72	Α
Avalanche Energy (L = 0.1mH)			E <sub>AS</sub>	262	mJ

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25$ °C	$P_D$	3.4	W
Thermal Resistance, Junction to Ambient (Note 5)  Steady State		RθJA	36.5	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	104	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	1.2	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

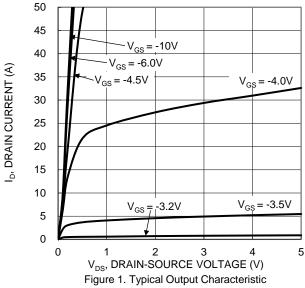
<b>0</b> 1			-			T (0 III)	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	V	$V_{GS} = 0V$ , $I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	-2.0	_	-3.0	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$	
Static Drain-Source On-Resistance	Dagger		3.6	5.2	mΩ	$V_{GS} = -10V, I_{D} = -9.8A$	
Static Drain-Source On-Resistance	RDS(ON)		4.5	7.9	1112.2	$V_{GS} = -6V, I_D = -9.8A$	
Diode Forward Voltage	VsD		-0.7	-1	V	$V_{GS} = 0V$ , $I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	6855	_		V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V f = 1MHz	
Output Capacitance	Coss	_	883	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg	_	7.8	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg		162	_		$V_{DS} = -20V, I_{D} = -9.8A$	
Gate-Source Charge	Qgs	_	28	_	nC		
Gate-Drain Charge	$Q_{gd}$	_	38	_			
Turn-On Delay Time	t <sub>D(ON)</sub>		28			$V_{GS} = -10V$ , $V_{DD} = -20V$ , $R_{G} = 6\Omega$ , $I_{D} = -9.8A$	
Turn-On Rise Time	t <sub>R</sub>	_	32	_			
Turn-Off Delay Time	tD(OFF)		469	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	1	228				
Reverse Recovery Time	trr		44		ns	$I_F = -9.8A$ , $di/dt = -100A/\mu s$	
Reverse Recovery Charge	Qrr		48	_	nC	$I_F = -9.8A$ , $di/dt = -100A/\mu s$	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

- 5. Device involved on the dark possible of solid point (on the exposed drain pad).
  6. Thermal resistance from junction to soldering point (on the exposed drain pad).
  7. Short duration pulse test used to minimize self-heating effect.
  8. Guaranteed by design. Not subject to product testing.

DMP4006SPSWQ 2 of 7 April 2021 © Diodes Incorporated Document number: DS43085 Rev. 2 - 2





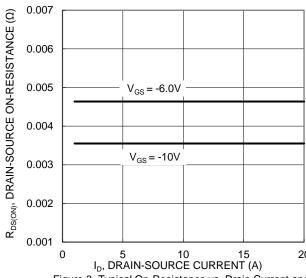


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

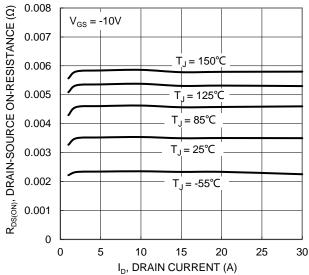
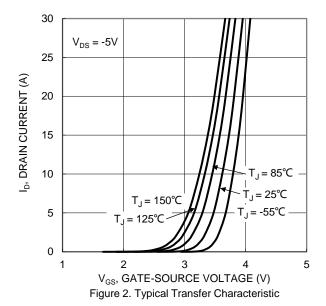


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature



0.04

O.03

O.02

O.02

O.02

O.02

O.03

O.02

O.02

O.03

O.02

O.04

O.05

O.05

O.05

O.05

O.07

O.07

O.08

O.09

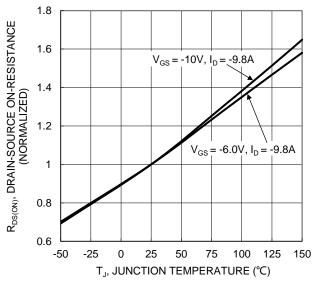
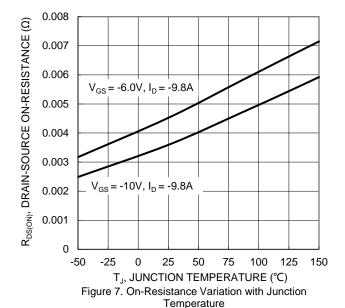
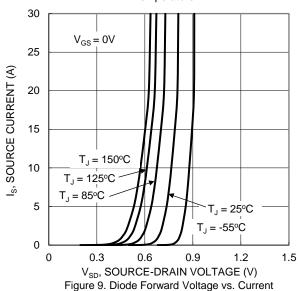
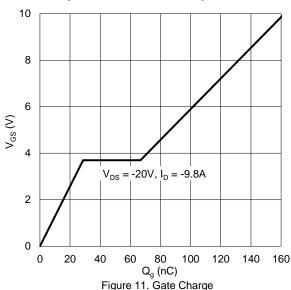


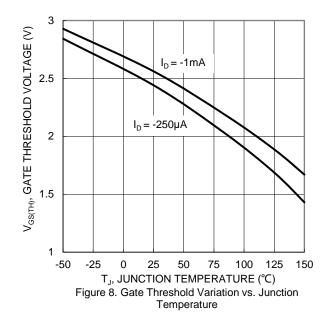
Figure 6. On-Resistance Variation with Junction Temperature





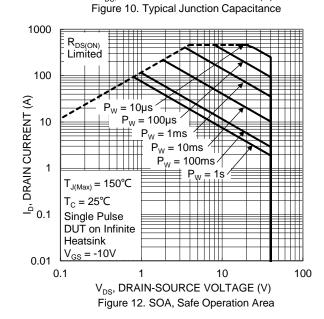






100000

| Coss |





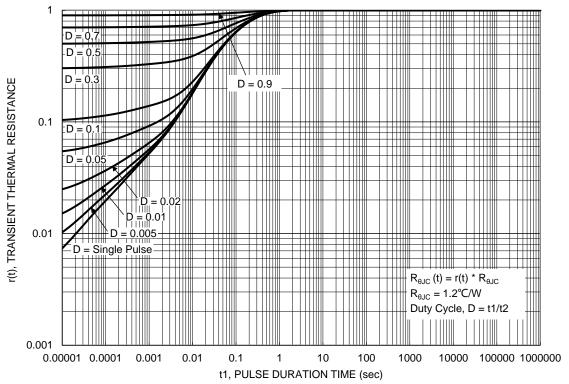


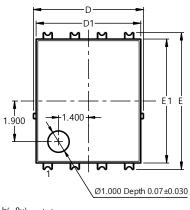
Figure 13. Transient Thermal Resistance

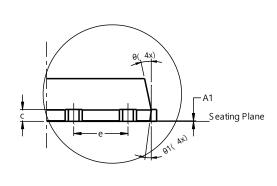


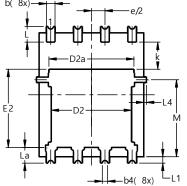
# **Package Outline Dimensions**

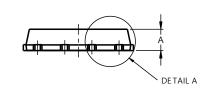
Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (SWP) (Type UX)









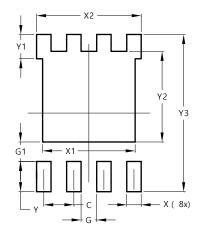
DETAIL A

PowerDI5060-8 (SWP)						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	0.25REF					
С	0.230	0.330	0.277			
D	5.15 BSC					
D1	4.70	5.10	4.90			
D2	3.56	3.96	3.76			
D2a	3.78	4.18	3.98			
Е	6.40 BSC					
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1.27BSC					
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
L1a	0.050REF					
L4	0.025	0.225	0.125			
M	3.205	4.005	3.605			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value		
	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



#### **IMPORTANT NOTICE**

- 1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and
- Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- provided subject to Diodes' Standard Terms and Conditions Sale Diodes products are (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing. Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com

7 of 7 DMP4006SPSWQ April 2021 © Diodes Incorporated Document number: DS43085 Rev. 2 - 2

# 单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))